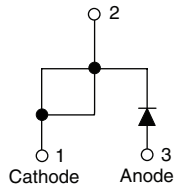
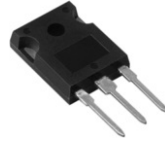
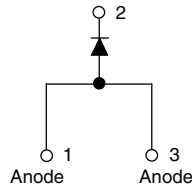


Ultrafast Soft Recovery Diode, 60 A FRED Pt™

60EPU04PbF

 Cathode
to base

TO247AC modified
60APU04PbF

 Cathode
to base

TO-247AC

FEATURES

- Ultrafast recovery
- 175 °C operating junction temperature
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level


RoHS*
COMPLIANT

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

PRODUCT SUMMARY

t_{rr}	50 ns
$I_{F(AV)}$	60 A
V_R	400 V

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	V_R		400	V
Continuous forward current	$I_{F(AV)}$	$T_C = 127\text{ °C}$	60	A
Single pulse forward current	I_{FSM}	$T_C = 25\text{ °C}$	600	
Maximum repetitive forward current	I_{FRM}	Square wave, 20 kHz	120	
Operating junction and storage temperatures	T_J, T_{Stg}		- 55 to 175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\text{ }\mu\text{A}$	400	-	-	V
Forward voltage	V_F	$I_F = 60\text{ A}$	-	1.05	1.25	
		$I_F = 60\text{ A}, T_J = 175\text{ °C}$	-	0.87	1.03	
		$I_F = 60\text{ A}, T_J = 125\text{ °C}$	-	0.93	1.10	
Reverse leakage current	I_R	$V_R = V_R$ rated	-	-	50	μA
		$T_J = 150\text{ °C}, V_R = V_R$ rated	-	-	2	mA
Junction capacitance	C_T	$V_R = 400\text{ V}$	-	50	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body	-	3.5	-	nH

* Pb containing terminations are not RoHS compliant, exemptions may apply

60EPU04PbF/60APU04PbF



Vishay High Power Products Ultrafast Soft Recovery Diode,
60 A FRED Pt™

DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	$I_F = 1\text{ A}$, $dI_F/dt = 200\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$		-	50	60	ns
		$T_J = 25\text{ }^\circ\text{C}$	$I_F = 60\text{ A}$ $dI_F/dt = 200\text{ A}/\mu\text{s}$ $V_R = 200\text{ V}$	-	85	-	
		$T_J = 125\text{ }^\circ\text{C}$		-	145	-	
Peak recovery current	I_{RRM}	$T_J = 25\text{ }^\circ\text{C}$	$I_F = 60\text{ A}$ $dI_F/dt = 200\text{ A}/\mu\text{s}$ $V_R = 200\text{ V}$	-	8.8	-	A
		$T_J = 125\text{ }^\circ\text{C}$		-	15.4	-	
Reverse recovery charge	Q_{rr}	$T_J = 25\text{ }^\circ\text{C}$	$I_F = 60\text{ A}$ $dI_F/dt = 200\text{ A}/\mu\text{s}$ $V_R = 200\text{ V}$	-	375	-	nC
		$T_J = 125\text{ }^\circ\text{C}$		-	1120	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R_{thJC}			-	-	0.70	K/W
Thermal resistance, case to heatsink	R_{thCS}	Mounting surface, flat, smooth and greased		-	0.2	-	
Weight				-	5.5	-	g
				-	0.2	-	oz.
Mounting torque				1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style TO-247AC modified		60EPU04			
		Case style TO-247AC		60APU04			

60EPU04PbF/60APU04PbF

Vishay High Power Products Ultrafast Soft Recovery Diode,
60 A FRED Pt™



ORDERING INFORMATION TABLE

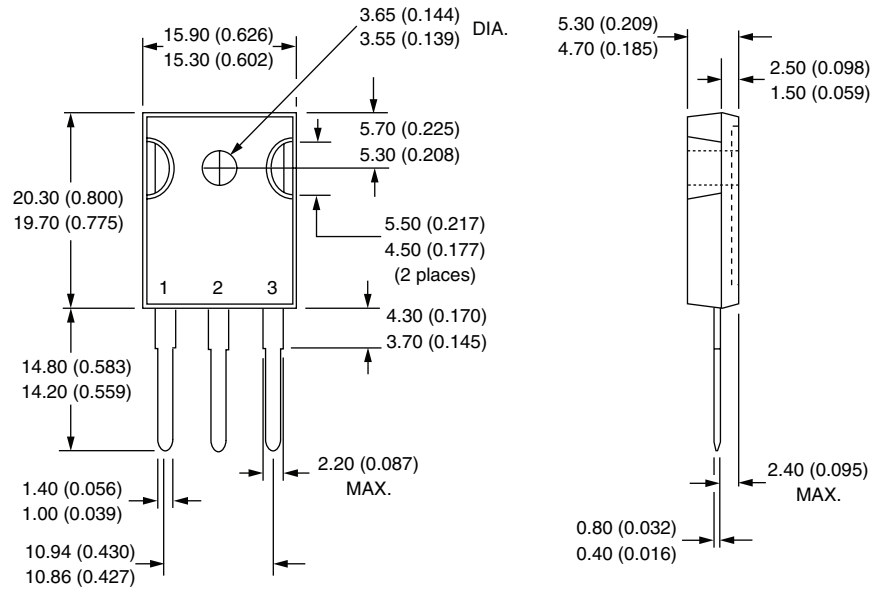
Device code	60	E	P	U	04	PbF
	①	②	③	④	⑤	⑥

- 1** - Current rating (60 = 60 A)
- 2** - Circuit configuration:
 - E = Single diode
 - A = Single diode, 3 pins
- 3** - Package:
 - P = TO-247AC (modified)
- 4** - Type of silicon:
 - U = Ultrafast recovery
- 5** - Voltage rating (04 = 400 V)
- 6** -
 - None = Standard production
 - PbF = Lead (Pb)-free

TO-247, TO-247 modified

DIMENSIONS in millimeters (inches)

Case style TO-247



Case style TO-247 (modified)

